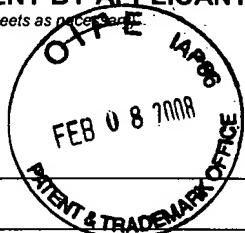


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**INFORMATION DISCLOSURE
STATEMENT BY APPLICANT**

(Use as many sheets as necessary)



Sheet 1 of 4

Complete if Known

Application Number	09/945,535
Filing Date	August 30, 2001
First Named Inventor	Ahn, Kie
Group Art Unit	2813
Examiner Name	Rodgers, Colleen

Attorney Docket No: 1303.026US1

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Sheet 2 of 4		Attorney Docket No: 1303.026US1											

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Sheet 3 of 4		Attorney Docket No: 1303.026US1	

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Sheet 4 of 4		Attorney Docket No: 1303.026US1	

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